TOSHIBA Photocoupler IRED & Photo-Transistor

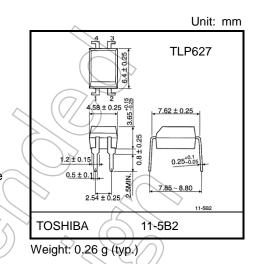
# TLP627, TLP627-2, TLP627-4

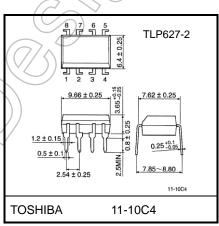
### **Programmable Controllers DC-output Module** Telecommunication

The TOSHIBA TLP627,-2 and -4 consist of an infrared emitting diode optically coupled to a Darlington connected phototransistor which has an integral base-emitter resistor to optimize switching speed and elevated temperature characteristics.

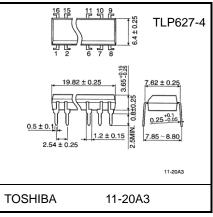
The TLP627-2 offers two isolated channels in eight lead plastic DIP, while the TLP627-4 provide four isolated channels per package.

- Collector-Emitter Voltage
  - : 300 V (min) Current Transfer Ratio
- **UL-recognized**
- : 1000 % (min)
- cUL-recognized
- : UL 1577, File No.E67349 No.5A File No.E67349
- VDE-approved
- : CSA Component Acceptance Service
- : EN 60747-5-5 (Note 1)
- Note 1: When a VDE approved type is needed, please designate the **Option(D4)**.





Weight: 0.54 g (typ.)

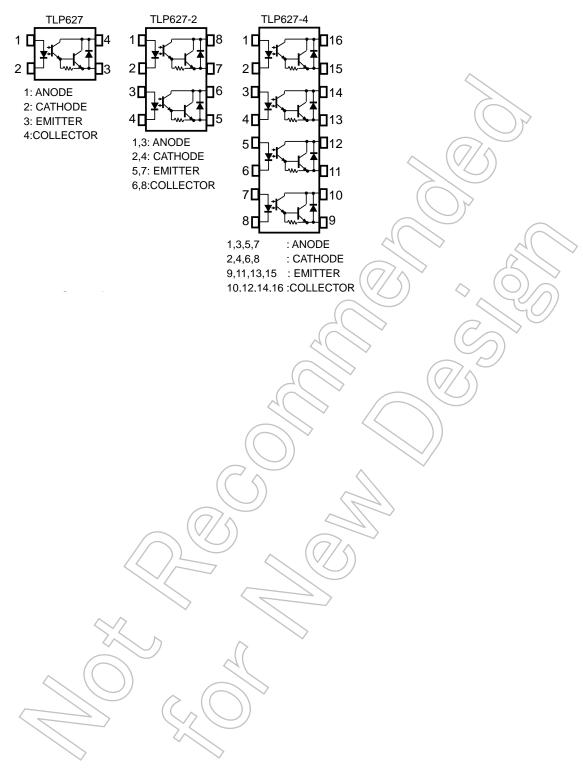


Weight: 1.1 g (typ.)

Start of commercial production 1984-08

# TOSHIBA

#### Pin Configuration (top view)



#### Absolute Maximum Ratings (Ta=25°C)

				Ratin		
Characteristics		Symbol	TLP627 TLP627-2 TLP627-4		Unit	
	Forward Current		lF	60 50		mA
	Forward Current Derating		∆IF /°C	-0.7(Ta≥39°C) -0.5(Ta≥25°C)		mA /°C
Δ	Pulse Forward Current		lfp	1 (100µs puls	А	
Reverse Voltage		VR	5	V		
	Diode Power Dissipation	(1 Circuit)	PD	100	70	mW
	Diode Power Dissipation Derating	(1 Circuit)	$\Delta P_D / C$	-1.2 (Ta≥39°C)	-0.7 (Ta≥25°C)	mW /°C
	Collector-Emitter Voltage Emitter -Collector Voltage Collector Current		VCEO	300	V	
or			VECO	0.3	V	
etect			lc	150	mA	
ă	Collector Power Dissipation	(1 Circuit)	Pc	150(300(Note 1)) 100		mW
	Collector Power Dissipation Derating (Ta	≥25°C,1 Circuit)	∆ Pc /°C	-1.5(-3.5(Note 1))	-1.0	mW /°C
Ope	erating Temperature Range		Topr	-55 to	100	°C
Storage Temperature Range		Tstg	-55 to 125		°C	
Lea	d Soldering Temperature	2	T <sub>sol</sub>	260(10	) s)	°C
Tota	al Package Power Dissipation	(1 Circuit)	Рт	250(320(Note 1))	150	mW
Tota	al Package Power Dissipation Derating (Ta≥	25°C,1 Circuit)	∆ P <sub>T</sub> /°C	-2.5(-3.2(Note 1))	-1.5	mW /°C
Isola	ation Voltage (AC,60 s, R.H. $\leq$ 60 %)	(Note 2)	BVs	5000	)	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: I<sub>F</sub>=20 mA Max

### **Recommended Operating Conditions**

Characteristics	Symbol	Min	Тур.	Max	Unit
Supply Voltage	Vcc	_	_	200	V
Forward Current	(JF)	_	16	25	mA
Collector Current	tc	—	—	120	mA
Operating Temperature	Topr	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Note 2: Device considered a two terminal device : LED side pins Shorted together and DETECTOR side pins shorted together.

### **Electrical Characteristics (Ta=25°C)**

	Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward Voltage	VF	I <sub>F</sub> = 10 mA	1.0	1.15	1.3	V
LED	Reverse Current	IR	V <sub>R</sub> = 5 V		—	10	μA
	Capacitance	Ст	V = 0 V, f = 1MHz		30		pF
	Collector-Emitter Breakdown Voltage	V(BR)CEO	IC = 0.1mA	300	$\overline{\bigcirc}$	>-	V
tor	Emitter-Collector Breakdown Voltage	V <sub>(BR)ECO</sub>	I <sub>E</sub> = 0.1mA	0.3		_	V
Detector	Collector Dark Current	1050	V <sub>CE</sub> = 200V	Y,	10	200	nA
		ICEO	V <sub>CE</sub> = 200V, Ta = 85 °C	1	-	20	μA
	Capacitance Collector to Emitter	CCE	V = 0 V, f = 1MHz	$\sum$	10		pF

### Coupled Electrical Characteristics (Ta=25°C)

oupled Electrical Chara	acteristics (Ta	a=25°C)	>> ,			
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Current Transfer Ratio	IC/IF	IF = 1 mA, VCE = 1 V	1000	4000	—	%
Saturated CTR	IC/IF(sat)	IF = 10 mA, VCE = 1 V	500		—	%
Collector-Emitter	Vce(sat) 🖉	IC = 10 mA, IF = 1 mA		—	1.0	V
Saturation Voltage	VCE(Sat)	IC = 100 mA, IF = 10 mA	0.3	—	1.2	v

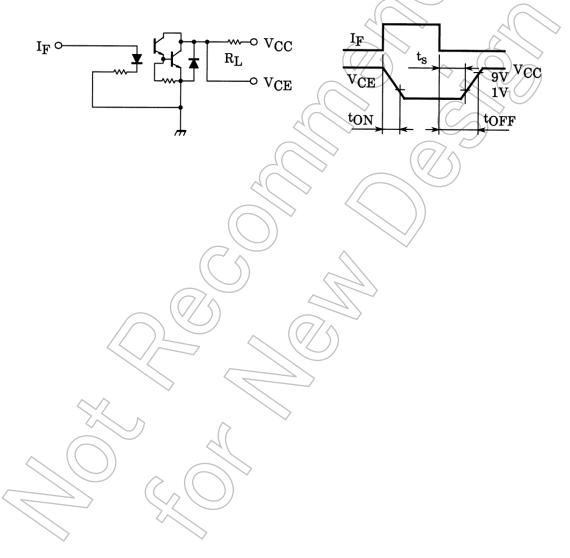
### Isolation Electrical Characteristics (Ta=25°C)

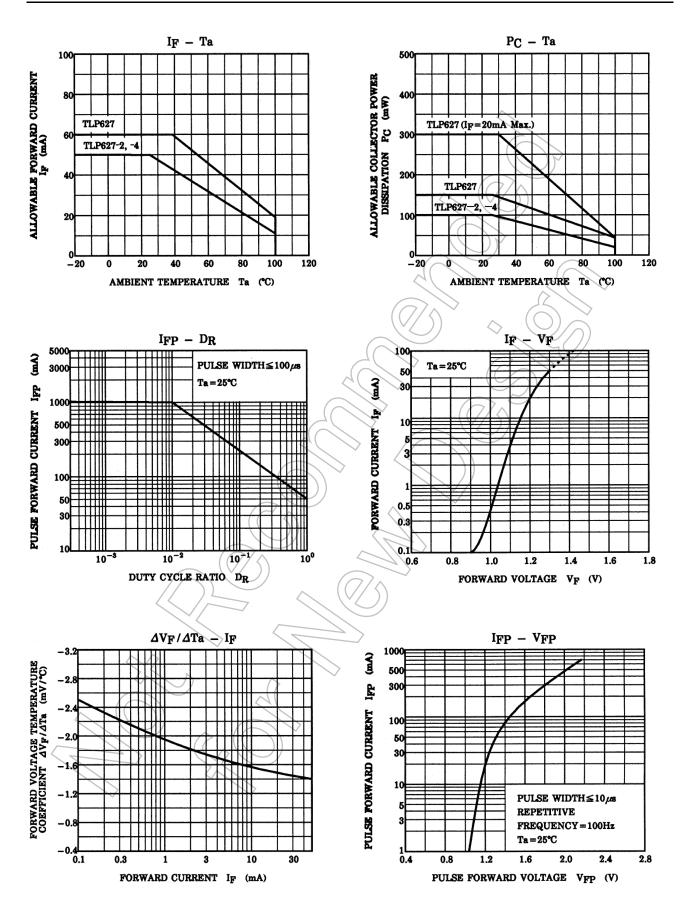
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance Input to Output	Cs <	$V_S = 0 V$ , $f = 1 MHz$	_	0.8	—	pF
Isolation Resistance	Z Rs	Vs = 500 V, R.H .≤ 60 %	5×10 <sup>10</sup>	10 <sup>14</sup>	—	Ω
Isolation Voltage	BVs	AC, 60 s	5000	_	_	Vrms

### Switching Characteristics (Ta=25°C)

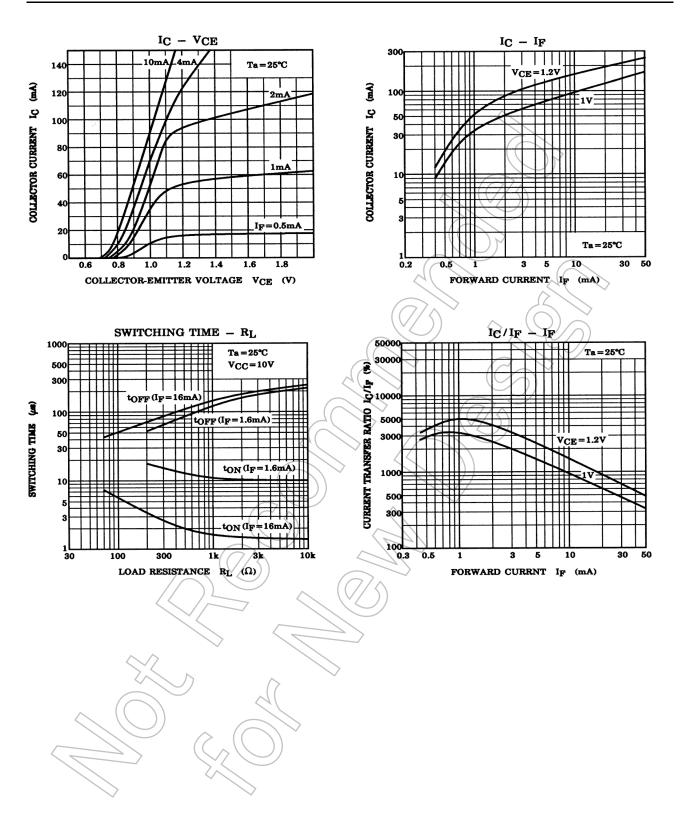
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Rise Time	tr		—	40	_	
Fall Time	tf	$V_{CC} = 10 V$ $I_C = 10 mA$ $R_L = 100 Ω$ $I_{RL} = 180 Ω$ (Fig.1) $V_{CC} = 10 V$ , IF = 16 mA	_	15	_	
Turn-on Time	ton		_ <	50	_	
Turn-off Time	t <sub>off</sub>		- (	15	1	μs
Turn-on Time	ton		_ '	5	) –     (	
Strage Time	ts		fa)	40	_	
Turn-off Time	tOFF		K K K	80	_	

#### Fig.1 Switching Time Test Circuit

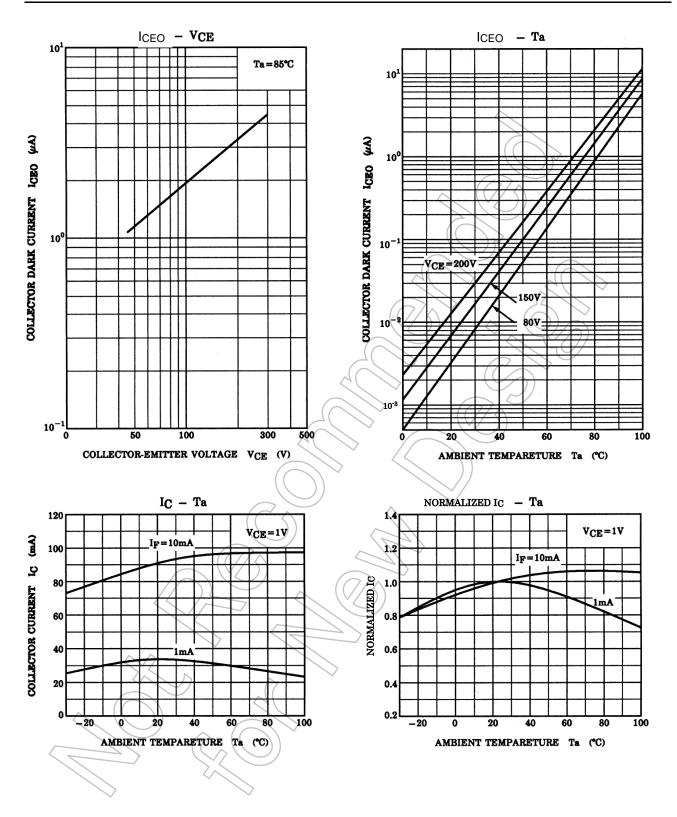




NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

### **RESTRICTIONS ON PRODUCT USE**

Toshiba Corporation and its subsidiaries and affiliates are collectively referred to as "TOSHIBA". Hardware, software and systems described in this document are collectively referred to as "Product".

- TOSHIBA reserves the right to make changes to the information in this document and related Product without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT ("UNINTENDED USE"). Except for specific applications as expressly stated in this document, Unintended Use includes, without limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, lifesaving and/or life supporting medical equipment, equipment used for automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to control combustions or explosions, safety devices, elevators and escalators, and devices related to power plant. IF YOU USE PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For details, please contact your TOSHIBA sales representative or contact us via our website.
- · Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- GaAs (Gallium Arsenide) is used in Product. GaAs is harmful to humans if consumed or absorbed, whether in the form of dust or vapor. Handle with care and do not break, cut, crush, grind, dissolve chemically or otherwise expose GaAs in Product.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without
  limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile
  technology products (mass destruction weapons). Product and related software and technology may be controlled under the
  applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the
  U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited
  except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.

### **TOSHIBA ELECTRONIC DEVICES & STORAGE CORPORATION**

https://toshiba.semicon-storage.com/

## **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

 $\frac{\text{Toshiba}:}{\frac{\text{TLP627(F)}}{2}}$